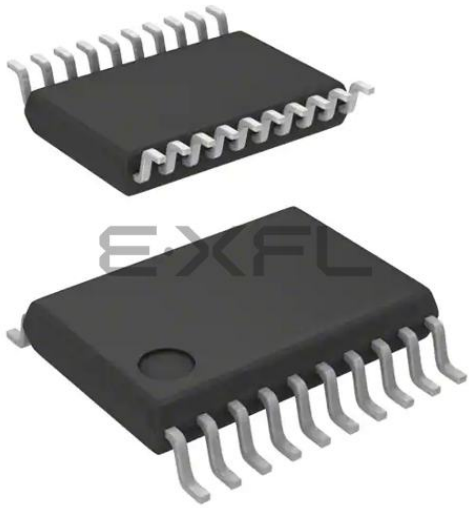
Renesas Electronics America Inc - R5F212H2SNSP#U0 Datasheet



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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	R8C
Core Size	16-Bit
Speed	8MHz
Connectivity	LINbus, SIO, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	15
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	384 x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	20-LSSOP (0.173", 4.40mm Width)
Supplier Device Package	20-LSSOP
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f212h2snsp-u0

Table 1.2 Specifications for R8C/2J Group

Item	Function	Specification
CPU	Central processing unit	R8C/Tiny series core • Number of fundamental instructions: 89 • Minimum instruction execution time: 125 ns (System clock = 8 MHz, VCC = 2.7 to 5.5 V) 250 ns (System clock = 4 MHz, VCC = 2.2 to 5.5 V) • Multiplier: 16 bits × 16 bits → 32 bits • Multiply-accumulate instruction: 16 bits × 16 bits + 32 bits → 32 bits • Operation mode: Single-chip mode (address space: 1 Mbyte)
Memory	ROM, RAM	Refer to **Table 1.4 Product List for R8C/2J Group**.
Power Supply Voltage Detection	Voltage detection circuit	• Power-on reset • Voltage detection 3
Comparator		• 2 circuits (shared with voltage monitor 1 and voltage monitor 2) • External reference voltage input is available
I/O Ports		CMOS I/O ports: 12, selectable pull-up resistor
Clock	Clock generation circuits	• 1 circuits: On-chip oscillator (high-speed, low-speed) (high-speed on-chip oscillator has a frequency adjustment function), • Frequency divider circuit: Dividing selectable 1, 2, 4, 8, and 16 • Low power consumption modes: Standard operating mode (high-speed on-chip oscillator, low-speed on-chip oscillator), wait mode, stop mode
Interrupts		• External: 3 sources, Internal: 14 sources, Software: 4 sources • Priority levels: 7 levels
Watchdog Timer		15 bits × 1 (with prescaler), reset start selectable
Timer	Timer RA	8 bits × 1 (with 8-bit prescaler) Timer mode (period timer), pulse output mode (output level inverted every period), event counter mode, pulse width measurement mode, pulse period measurement mode
	Timer RB	8 bits × 1 (with 8-bit prescaler) Timer mode (period timer), programmable waveform generation mode (PWM output), programmable one-shot generation mode, programmable wait one-shot generation mode
	Timer RE	Not implemented
	Timer RF	16 bits × 1 (with capture/compare register pin and compare register pin) Input capture mode, output compare mode
Serial Interface	UART0	Clock synchronous serial I/O/UART × 1
LIN Module		Hardware LIN: 1 (timer RA, UART0)
Flash Memory		• Programming and erasure voltage: VCC = 2.7 to 5.5 V • Programming and erasure endurance: 100 times • Program security: ROM code protect, ID code check • Debug functions: On-chip debug, on-board flash rewrite function
Operating Frequency/Supply Voltage		System clock = 8 MHz (VCC = 2.7 to 5.5 V) System clock = 4 MHz (VCC = 2.2 to 5.5 V)
Current consumption		5 mA (VCC = 5 V, system clock = 8 MHz) 23 μA (VCC = 3 V, wait mode (low-speed on-chip oscillator on)) 0.7 μA (VCC = 3 V, stop mode, BGR trimming circuit disabled)
Operating Ambient Temperature		-20 to 85°C (N version) -40 to 85°C (D version)(1)
Package		20-pin LSSOP Package code: PLSP0020JB-A (previous code: 20P2F-A)

NOTE:
1. Specify the D version if D version functions are to be used.

1.2 Product List

Table 1.3 lists Product List for R8C/2H Group, Figure 1.1 shows a Part Number, Memory Size, and Package of R8C/2H Group. Table 1.4 lists Product List for R8C/2J Group, Figure 1.2 shows a Part Number, Memory Size, and Package of R8C/2J Group.

Table 1.3 Product List for R8C/2H Group **Current of Mar. 2008**

Part No.	ROM Capacity	RAM Capacity	Package Type	Remarks
R5F212H1SNSP	4 Kbytes	256 bytes	PLSP0020JB-A	N version
R5F212H2SNSP	8 Kbytes	384 bytes	PLSP0020JB-A	
R5F212H1SDSP	4 Kbytes	256 bytes	PLSP0020JB-A	D version
R5F212H2SDSP	8 Kbytes	384 bytes	PLSP0020JB-A	

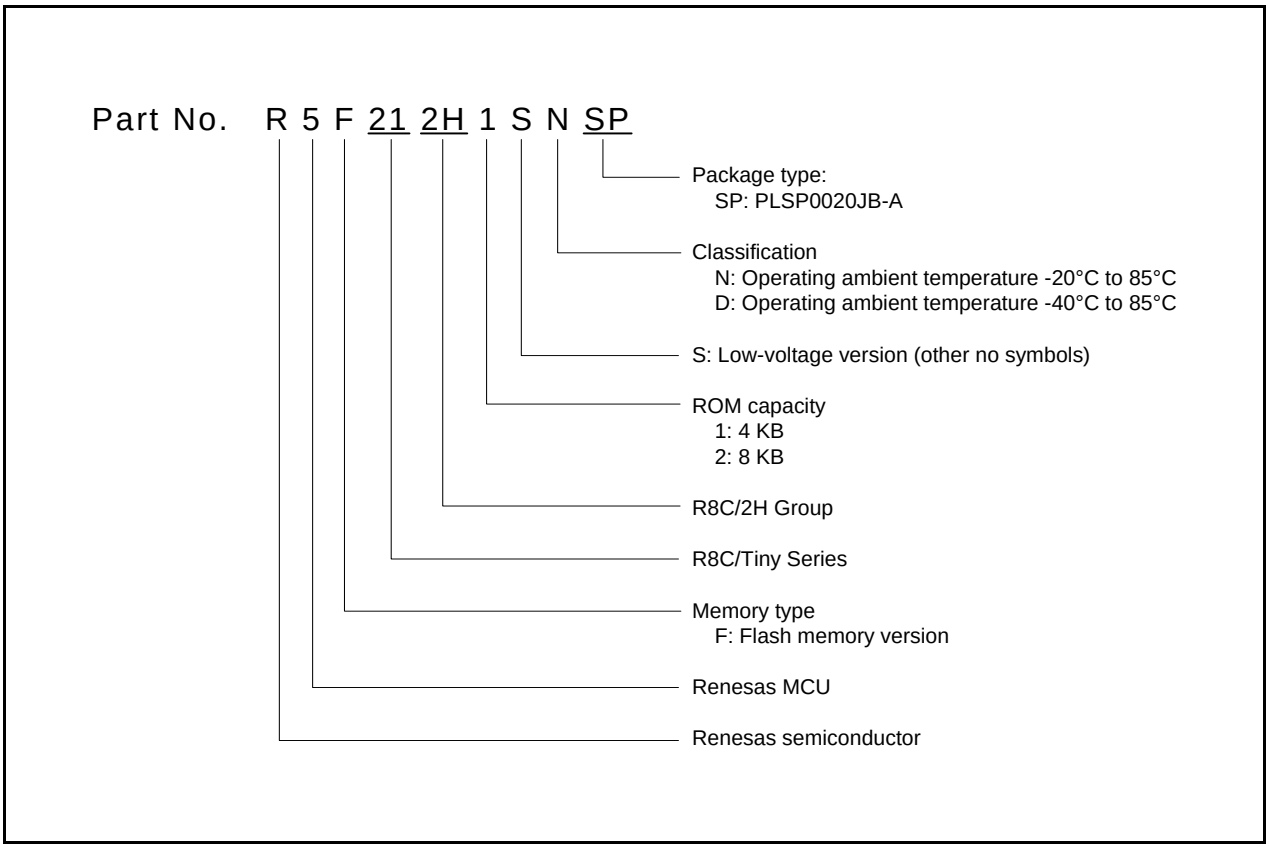


Figure 1.1 Part Number, Memory Size, and Package of R8C/2H Group

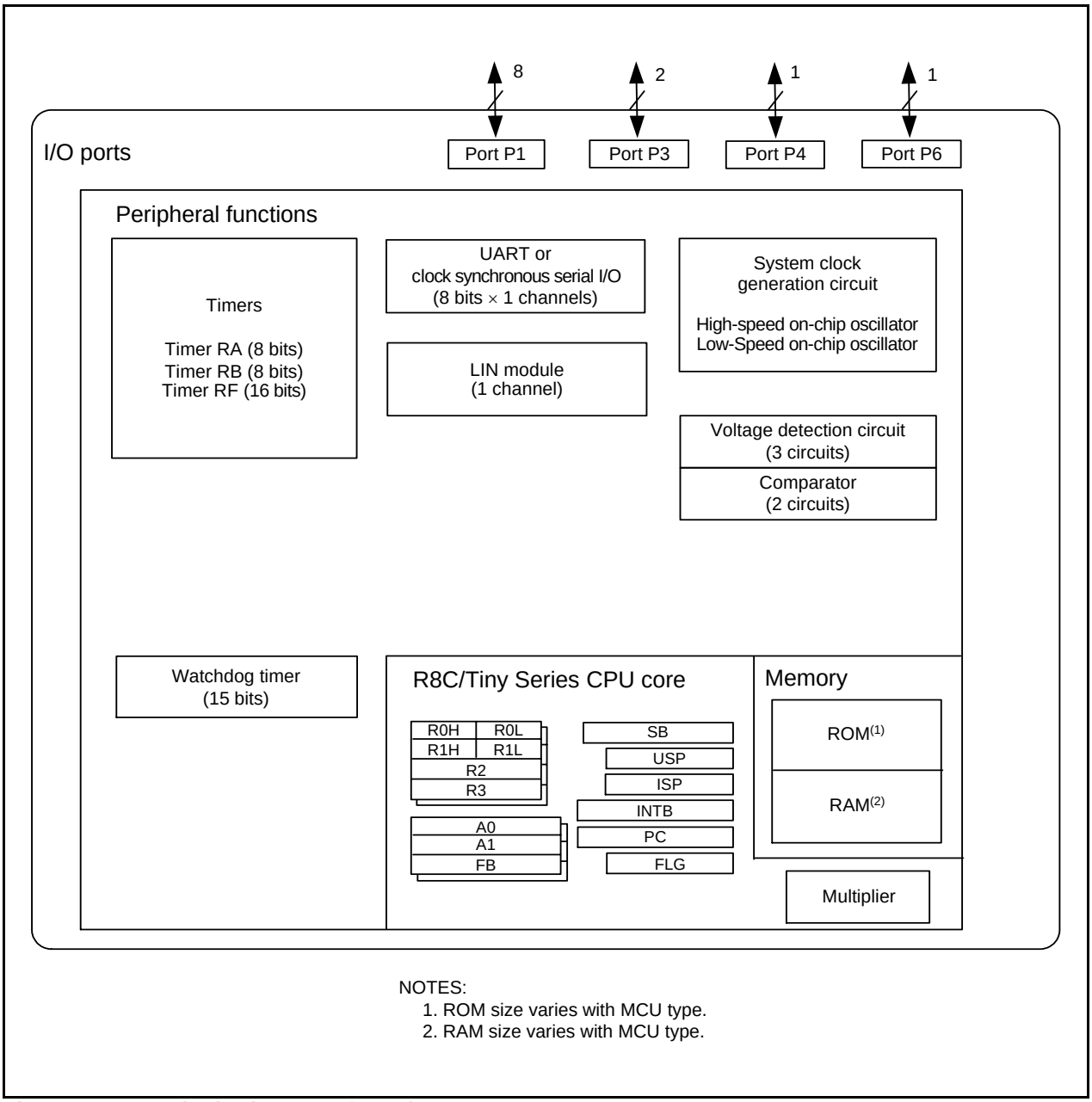


Figure 1.4 Block Diagram of R8C/2J Group

Table 1.6 Pin Name Information by Pin Number of R8C/2J Group

Pin Number	Control Pin	Port	I/O Pin Functions for of Peripheral Modules			
			Interrupt	Timer	Serial Interface	Comparator
1	NC(2)					
2		P3_7		TRAO/TRFO11		
3	$\overline{\text{RESET}}$					
4	NC(2)					
5	VSS					
6	NC(2)					
7	VCC					
8	MODE					
9		P4_5	$\overline{\text{INT0}}$			
10		P1_7	$\overline{\text{INT1}}$	TRAIO		
11		P1_6			CLK0	VCOUT2
12		P1_5	($\overline{\text{INT1}}$)(1)	(TRAIO)(1)	RXD0	
13		P1_4			TXD0	
14		P1_3	$\overline{\text{KI3}}$	TRBO		VCOUT1
15		P1_2	$\overline{\text{KI2}}$	TRFO02		CVREF
16		P6_5				
17		P1_1	$\overline{\text{KI1}}$	TRFO01		VCMP2
18		P1_0	$\overline{\text{KI0}}$	TRFO00		VCMP1
19		P3_3		TRFO10/TRFI		
20	NC(2)					

NOTES:
1. Can be assigned to the pin in parentheses by a program.
2. NC(Non-Connection)

2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.
Interrupt are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

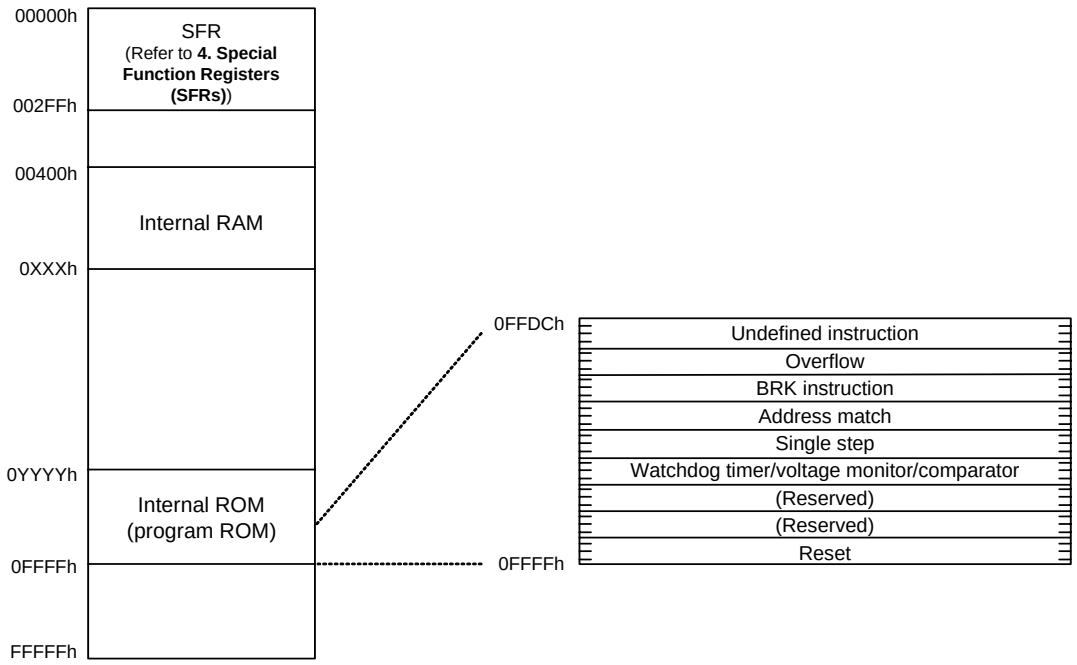
ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1.
The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7.
If a requested interrupt has higher priority than IPL, the interrupt is enabled.

2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.



NOTE:
1. The blank regions are reserved. Do not access locations in these regions.

Part Number	Internal ROM		Internal RAM	
	Size	Address 0YYYYh	Size	Address 0XXXXh
R5F212J0SNSP, R5F212J0SDSP	2 Kbytes	0F800h	256 bytes	004FFh
R5F212J1SNSP, R5F212J1SDSP	4 Kbytes	0F000h	384 bytes	0057Fh

Figure 3.2 Memory Map of R8C/2J Group

Table 4.2 SFR Information (2)(1)

Address	Register	Symbol	After reset
0030h			
0031h	Voltage Detection Register 1(2)	VCA1	00001000b
0032h	Voltage Detection Register 2(2)	VCA2	00h(3) 00100000b(4)
0033h			
0034h			
0035h			
0036h	Voltage Monitor 1 Circuit Control Register(5)	VW1C	00001010b
0037h	Voltage Monitor 2 Circuit Control Register(5)	VW2C	00000010b
0038h	Voltage Monitor 0 Circuit Control Register(2)	VW0C	1000X010b(3) 1100X011b(4)
0039h			
003Ah			
003Bh	Voltage Detection Circuit External Input Control Register	VCAB	00h
003Ch	Comparator Mode Register	ALCMR	00h
003Dh	Voltage Monitor Circuit Edge Select Register	VCAC	00h
003Eh	BGR Control Register	BGRCR	00h
003Fh	BGR Trimming Register	BGRTRM	When Shipping
0040h			
0041h	Comparator 1 Interrupt Control Register	VCMP1IC	XXXXX000b
0042h	Comparator 2 Interrupt Control Register	VCMP2IC	XXXXX000b
0043h			
0044h			
0045h			
0046h			
0047h			
0048h			
0049h			
004Ah	Timer RE Interrupt Control Register(6)	TREIC	XXXXX000b
004Bh	UART2 Transmit Interrupt Control Register(6)	S2TIC	XXXXX000b
004Ch	UART2 Receive Interrupt Control Register(6)	S2RIC	XXXXX000b
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh			
004Fh			
0050h	Compare 1 Interrupt Control Register	CMP1IC	XXXXX000b
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXXX000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXXX000b
0053h			
0054h			
0055h			
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah			
005Bh	Timer RF Interrupt Control Register	TRFIC	XXXXX000b
005Ch	Compare 0 Interrupt Control Register	CMP0IC	XXXXX000b
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh			
005Fh	Capture Interrupt Control Register	CAPIC	XXXXX000b
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh			
006Ch			
006Dh			
006Eh			
006Fh			

X: Undefined

NOTES:
1. The blank regions are reserved. Do not access locations in these regions.
2. Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register.
3. The LVD0ON bit in the OFS register is set to 1 and hardware reset.
4. Power-on reset, voltage monitor 0 reset, or the LVD0ON bit in the OFS register is set to 0 and hardware reset.
5. Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect b2 and b3.
6. This register is not implemented in the R8C/2J Group.

Table 4.3 SFR Information (3)(1)

Address	Register	Symbol	After reset
0070h			
0071h			
0072h			
0073h			
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
007Ah			
007Bh			
007Ch			
007Dh			
007Eh			
007Fh			
0080h			
0081h			
0082h			
0083h			
0084h			
0085h			
0086h			
0087h			
0088h			
0089h			
008Ah			
008Bh			
008Ch			
008Dh			
008Eh			
008Fh			
0090h			
0091h			
0092h			
0093h			
0094h			
0095h			
0096h			
0097h			
0098h			
0099h			
009Ah			
009Bh			
009Ch			
009Dh			
009Eh			
009Fh			
00A0h	UART0 Transmit/Receive Mode Register	U0MR	00h
00A1h	UART0 Bit Rate Register	U0BRG	XXh
00A2h	UART0 Transmit Buffer Register	U0TB	XXh
00A3h			XXh
00A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
00A5h	UART0 Transmit/Receive Control Register 1	U0C1	00000010b
00A6h	UART0 Receive Buffer Register	U0RB	XXh
00A7h			XXh
00A8h			
00A9h			
00AAh			
00ABh			
00ACh			
00ADh			
00AEh			
00AFh			

X: Undefined
NOTE:
1. The blank regions are reserved. Do not access locations in these regions.

Table 4.8 SFR Information (8)(1)

Address	Register	Symbol	After reset
01B0h			
01B1h			
01B2h			
01B3h	Flash Memory Control Register 4	FMR4	01000000b
01B4h			
01B5h	Flash Memory Control Register 1	FMR1	1000000Xb
01B6h			
01B7h	Flash Memory Control Register 0	FMR0	00000001b
01B8h			
01B9h			
01BAh			
01BBh			
01BCh			
01BDh			
01BEh			
01BFh			
01C0h			
01C1h			
01C2h			
01C3h			
01C4h			
01C5h			
01C6h			
01C7h			
01C8h			
01C9h			
01CAh			
01CBh			
01CCh			
01CDh			
01CEh			
01CFh			
01D0h			
01D1h			
01D2h			
01D3h			
01D4h			
01D5h			
01D6h			
01D7h			
01D8h			
01D9h			
01DAh			
01DBh			
01DCh			
01DDh			
01DEh			
01DFh			
01E0h			
01E1h			
01E2h			
01E3h			
01E4h			
01E5h			
01E6h			
01E7h			
01E8h			
01E9h			
01EAh			
01EBh			
01ECh			
01EDh			
01EEh			
01EFh			

X: Undefined
NOTE:
1. The blank regions are reserved. Do not access locations in these regions.

Table 5.13 Electrical Characteristics (2) [Vcc = 5 V]
(Topr = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Condition		Standard			Unit
				Min.	Typ.	Max.	
ICC	Power supply current (VCC = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are VSS	High-speed on-chip oscillator mode	High-speed on-chip oscillator on = 8 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	5	8	mA
			High-speed on-chip oscillator on = 8 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2	–	mA
		Low-speed on-chip oscillator mode	High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	–	130	300	µA
		Low-speed clock mode	High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) FMR47 = 1	–	130	300	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) Program operation on RAM Flash memory off, FMSTP = 1	–	30	–	µA
		Wait mode	High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	25	75	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	23	60	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit disabled (BGRCR0 = 1)	–	4	–	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit disabled (BGRCR0 = 1)	–	2.2	–	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit enabled (BGRCR0 = 0)	–	8	–	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit enabled (BGRCR0 = 0)	–	6	–	µA
		Stop mode	XCIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit disabled (BGRCR0 = 1)	–	0.8	3	µA
			XCIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit disabled (BGRCR0 = 1)	–	1.2	–	µA
			XCIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit enabled (BGRCR0 = 0)	–	5	8	µA
			XCIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit enabled (BGRCR0 = 0)	–	5.5	–	µA

Table 5.16 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	200	–	ns
$t_{W(CKH)}$	CLKi input “H” width	100	–	ns
$t_{W(CKL)}$	CLKi input “L” width	100	–	ns
$t_{d(C-Q)}$	TXDi output delay time	–	50	ns
$t_{h(C-Q)}$	TXDi hold time	0	–	ns
$t_{su(D-C)}$	RXDi input setup time	50	–	ns
$t_{h(C-D)}$	RXDi input hold time	90	–	ns

i = 0 or 2

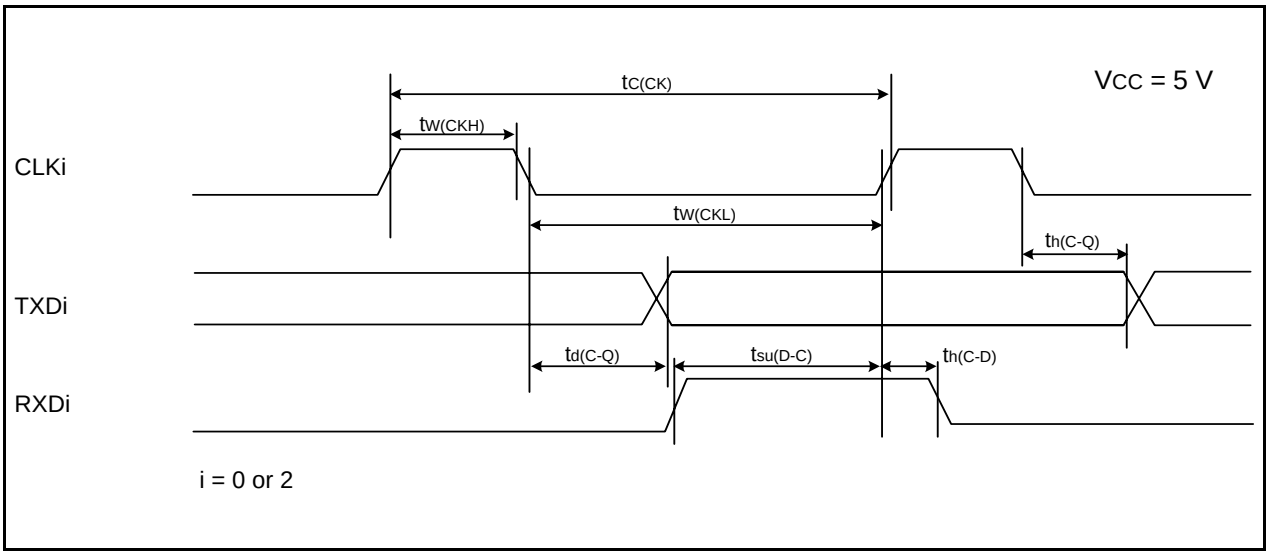


Figure 5.5 Serial Interface Timing Diagram when VCC = 5 V

Table 5.17 External Interrupt $\overline{INTi}$ (i = 0 or 1) Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{W(INH)}$	$\overline{INTi}$ input “H” width	250(1)	–	ns
$t_{W(INL)}$	$\overline{INTi}$ input “L” width	250(2)	–	ns

NOTES:
1. When selecting the digital filter by the $\overline{INTi}$ input filter select bit, use an $\overline{INTi}$ input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the $\overline{INTi}$ input filter select bit, use an $\overline{INTi}$ input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

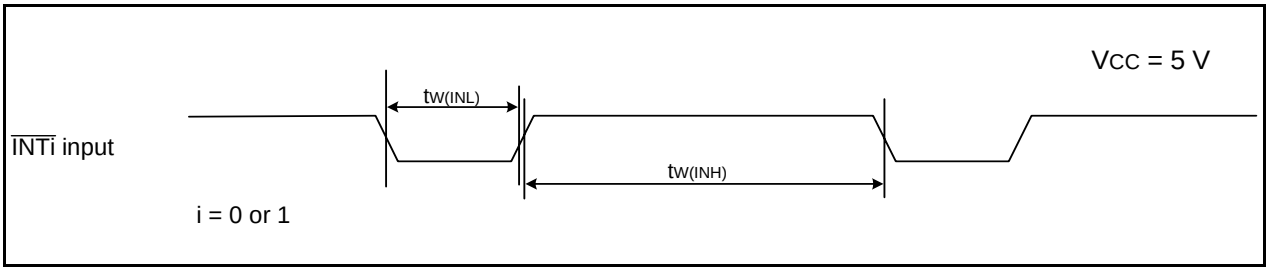


Figure 5.6 External Interrupt $\overline{INTi}$ Input Timing Diagram when VCC = 5 V

Table 5.18 Electrical Characteristics (3) [V_{CC} = 3 V]

Symbol	Parameter		Condition	Standard			Unit
				Min.	Typ.	Max.	
V_{OH}	Output “H” voltage		I_{OH} = –1 mA	V_{CC} – 0.5	–	V_{CC}	V
V_{OL}	Output “L” voltage		I_{OL} = 1 mA	–	–	0.5	V
V_{T+}-V_{T-}	Hysteresis	$\overline{INT0}$, $\overline{INT1}$, $\overline{KI0}$, $\overline{KI1}$, $\overline{KI2}$, $\overline{KI3}$, RXD0, RXD2, CLK0, CLK2		0.1	0.3	–	V
		$\overline{RESET}$		0.1	0.4	–	V
I_{IH}	Input “H” current		VI = 3 V, V_{CC} = 3 V	–	–	4.0	µA
I_{IL}	Input “L” current		VI = 0 V, V_{CC} = 3 V	–	–	–4.0	µA
R_{PULLUP}	Pull-up resistance		VI = 0 V, V_{CC} = 3 V	66	160	500	kΩ
R_{fXCIN}	Feedback resistance	XCIN		–	18	–	MΩ
V_{RAM}	RAM hold voltage		During stop mode	1.8	–	–	V

NOTE:
1. V_{CC} =2.7 to 3.3 V at T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.

Table 5.25 Electrical Characteristics (6) [Vcc = 2.2 V]
(Topr = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.)

Symbol	Parameter	Condition		Standard			Unit
				Min.	Typ.	Max.	
ICC	Power supply current (VCC = 2.2 to 2.7 V) Single-chip mode, output pins are open, other pins are VSS	High-speed on-chip oscillator mode	High-speed on-chip oscillator on = 4 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	3.5	–	mA
			High-speed on-chip oscillator on = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	1.5	–	mA
		Low-speed on-chip oscillator mode	High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	–	100	230	µA
		Low-speed clock mode	High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) FMR47 = 1	–	100	230	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) Program operation on RAM Flash memory off, FMSTP = 1	–	25	–	µA
		Wait mode	High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	22	60	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	–	20	55	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit disabled (BGRCR0 = 1)	–	3	–	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit disabled (BGRCR0 = 1)	–	1.8	–	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit enabled (BGRCR0 = 0)	–	7	–	µA
			High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1 BGR trimming circuit enabled (BGRCR0 = 0)	–	6	–	µA
		Stop mode	XCIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit disabled (BGRCR0 = 1)	–	0.7	3	µA
			XCIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit disabled (BGRCR0 = 1)	–	1.1	–	µA
			XCIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit enabled (BGRCR0 = 0)	–	5	7	µA
			XCIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0 BGR trimming circuit enabled (BGRCR0 = 0)	–	5.5	–	µA

5.2 R8C/2J Group

Table 5.30 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
V_{CC}	Supply voltage		–0.3 to 6.5	V
V_I	Input voltage		–0.3 to V_{CC} + 0.3	V
V_O	Output voltage		–0.3 to V_{CC} + 0.3	V
P_d	Power dissipation	T_{opr} = 25°C	500	mW
T_{opr}	Operating ambient temperature		–20 to 85 (N version) / –40 to 85 (D version)	°C
T_{stg}	Storage temperature		–65 to 150	°C

Table 5.31 Recommended Operating Conditions

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
V_{CC}	Supply voltage			2.2	–	5.5	V
V_{SS}	Supply voltage			–	0	–	V
V_{IH}	Input “H” voltage			0.8 V_{CC}	–	V_{CC}	V
V_{IL}	Input “L” voltage			0	–	0.2 V_{CC}	V
$I_{OH(sum)}$	Peak sum output “H” current	Sum of all pins $I_{OH(peak)}$		–	–	–160	mA
$I_{OH(sum)}$	Average sum output “H” current	Sum of all pins $I_{OH(avg)}$		–	–	–80	mA
$I_{OH(peak)}$	Peak output “H” current	All pins		–	–	–10	mA
$I_{OH(avg)}$	Average output “H” current	All pins		–	–	–5	mA
$I_{OL(sum)}$	Peak sum output “L” currents	Sum of all pins $I_{OL(peak)}$		–	–	160	mA
$I_{OL(sum)}$	Average sum output “L” currents	Sum of all pins $I_{OL(avg)}$		–	–	80	mA
$I_{OL(peak)}$	Peak output “L” currents	All pins		–	–	10	mA
$I_{OL(avg)}$	Average output “L” current	All pins		–	–	5	mA
–	System clock		HRA01 = 0 Low-speed on-chip oscillator selected	–	125	–	kHz
			HRA01 = 1 High-speed on-chip oscillator selected 2.7 V ≤ V_{CC} ≤ 5.5 V	–	–	8	MHz
			HRA01 = 1 High-speed on-chip oscillator selected 2.2 V ≤ V_{CC} ≤ 5.5 V	–	–	4	MHz

NOTES:
1. V_{CC} = 2.2 to 5.5 V at T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.
2. The average output current indicates the average value of current measured during 100 ms.

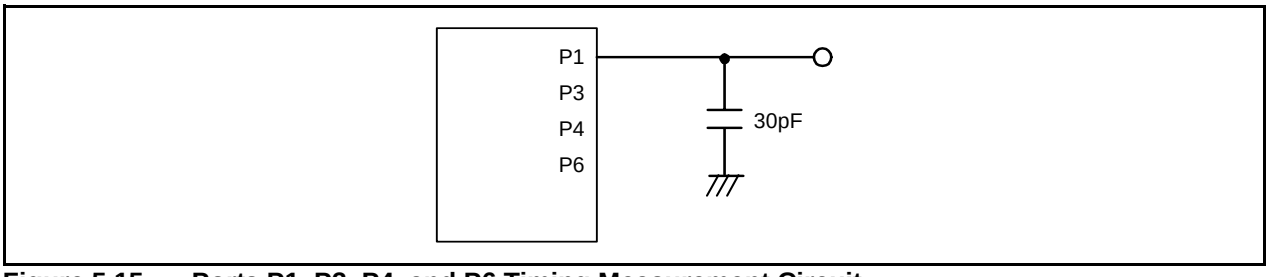


Figure 5.15 Ports P1, P3, P4, and P6 Timing Measurement Circuit

Table 5.32 Flash Memory (Program ROM) Electrical Characteristics

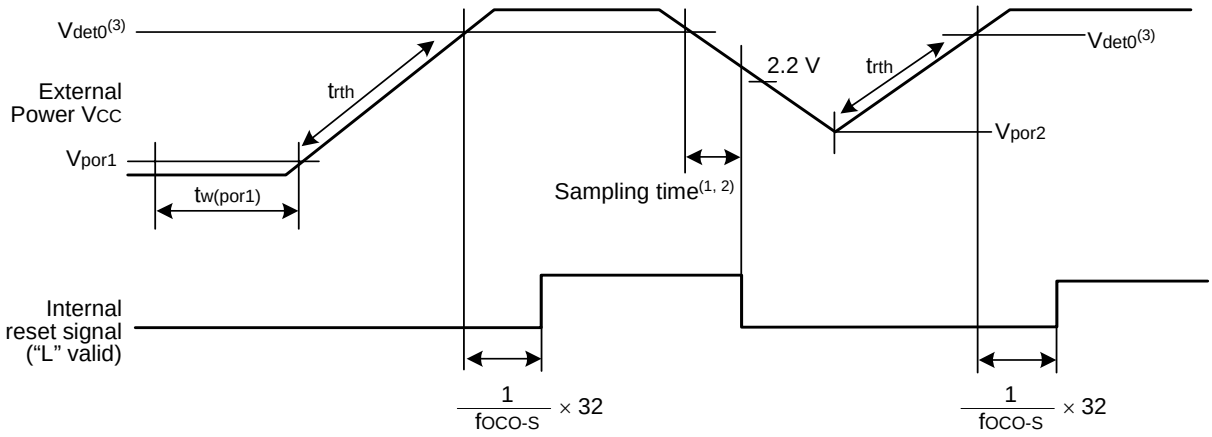
Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
–	Program/erase endurance(2)		100(3)	–	–	times
–	Byte program time		–	50	400	µs
–	Block erase time		–	0.4	9	s
–	Program, erase voltage		2.7	–	5.5	V
–	Read voltage		2.2	–	5.5	V
–	Program, erase temperature		0	–	60	°C
–	Data hold time(7)	Ambient temperature = 55°C	20	–	–	year

NOTES:
1. V_{CC} = 2.7 to 5.5 V at T_{opr} = 0 to 60°C, unless otherwise specified.
2. Definition of programming/erasure endurance
   The programming and erasure endurance is defined on a per-block basis.
   If the programming and erasure endurance is n (n = 100 or 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.
   However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erase count of each block and limit the number of erase operations to a certain number.
5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
7. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.36 Power-on Reset Circuit, Voltage Monitor 0 Reset Electrical Characteristics(3)

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
V_{por1}	Power-on reset valid voltage(4)		–	–	0.1	V
V_{por2}	Power-on reset or voltage monitor 0 reset valid voltage		0	–	V_{det0}	V
t_{rth}	External power V_{CC} rise gradient(2)		20	–	–	mV/msec

NOTES:
1. The measurement condition is T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.
2. This condition (external power V_{CC} rise gradient) does not apply if $V_{CC} \geq 1.0$ V.
3. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVD0ON bit in the OFS register to 0, the VW0C0 and VW0C6 bits in the VW0C register to 1 respectively, and the VCA25 bit in the VCA2 register to 1.
4. $t_{w(por1)}$ indicates the duration the external power V_{CC} must be held below the effective voltage (V_{por1}) to enable a power on reset. When turning on the power for the first time, maintain $t_{w(por1)}$ for 30 s or more if –20°C ≤ T_{opr} ≤ 85°C, maintain $t_{w(por1)}$ for 3,000 s or more if –40°C ≤ T_{opr} < –20°C.



NOTES:
1. When using the voltage monitor 0 digital filter, ensure that the voltage is within the MCU operation voltage range (2.2 V or above) during the sampling time.
2. The sampling clock can be selected. Refer to **6. Voltage Detection Circuit** of Hardware Manual for details.
3. V_{det0} indicates the voltage detection level of the voltage detection 0 circuit. Refer to **6. Voltage Detection Circuit** of Hardware Manual for details.

Figure 5.16 Reset Circuit Electrical Characteristics

Table 5.37 Comparator Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
Vref	Internal reference voltage	V_{CC} = 2.2 V to 5.5 V, T_{opr} = 25°C	1.15	1.25	1.35	V
		V_{CC} = 2.2 V to 5.5 V, T_{opr} = –40 to 85°C	–	1.25	–	V
Vcref	External input reference voltage	V_{CC} = 2.2 V to 4.0 V	0.5	–	V_{CC} – 1.1	V
		V_{CC} = 4.0 V to 5.5 V	0.5	–	V_{CC} – 1.5	V
Vcin	External comparison voltage input range		–0.3	–	V_{CC} + 0.3	V
Vofs	Input offset voltage		–	20	120	mV
Tcrsp	Response time		–	4	–	µs

NOTE:
1. The measurement condition is T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.

Table 5.38 High-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO-F	High-speed on-chip oscillator frequency temperature • supply voltage dependence	V_{CC} = 4.75 V to 5.25 V, T_{opr} = 0 to 60°C(2)	7.76	8	8.24	MHz
		V_{CC} = 2.7 V to 5.5 V, T_{opr} = –20 to 85°C(2)	7.68	8	8.32	MHz
		V_{CC} = 2.7 V to 5.5 V, T_{opr} = –40 to 85°C(2)	7.44	8	8.32	MHz
		V_{CC} = 2.2 V to 5.5 V, T_{opr} = –20 to 85°C(3)	7.04	8	8.96	MHz
		V_{CC} = 2.2 V to 5.5 V, T_{opr} = –40 to 85°C(3)	6.8	8	9.2	MHz

NOTES:
1. The measurement condition is T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.
2. These standard values show when the HRA1 register is set to the value before shipment and the HRA2 register is set to 00h.
3. These standard values show when the correction value in the FRA6 register is written into the HRA1 register.

Table 5.39 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
–	Oscillation stability time		–	10	100	µs
–	Self power consumption at oscillation	V_{CC} = 5.0 V, T_{opr} = 25°C	–	15	–	µA

NOTE:
1. V_{CC} = 2.2 to 5.5 V, T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.

Table 5.40 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
$t_{d(P-R)}$	Time for internal power supply stabilization during power-on(2)		1	–	2000	µs
$t_{d(R-S)}$	STOP exit time(3)		–	–	150	µs

NOTES:
1. The measurement condition is V_{CC} = 2.2 to 5.5 V and T_{opr} = 25°C.
2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

Timing Requirements
(Unless Otherwise Specified: V_{CC} = 5 V, V_{SS} = 0 V at T_{opr} = 25°C) [V_{CC} = 5 V]

Table 5.43 TRAIO Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRAIO)}$	TRAIO input cycle time	100	–	ns
$t_{WH(TRAIO)}$	TRAIO input “H” width	40	–	ns
$t_{WL(TRAIO)}$	TRAIO input “L” width	40	–	ns

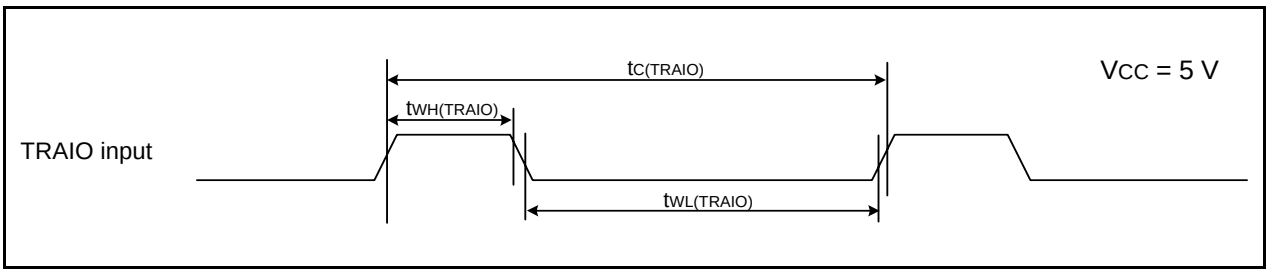


Figure 5.17 TRAIO Input Timing Diagram when V_{CC} = 5 V

Table 5.46 Electrical Characteristics (3) [V_{CC} = 3 V]

Symbol	Parameter		Condition	Standard			Unit
				Min.	Typ.	Max.	
V_{OH}	Output “H” voltage		I_{OH} = –1 mA	V_{CC} – 0.5	–	V_{CC}	V
V_{OL}	Output “L” voltage		I_{OL} = 1 mA	–	–	0.5	V
V_{T+}-V_{T-}	Hysteresis	$\overline{INT0}$, $\overline{INT1}$, $\overline{KI0}$, $\overline{KI1}$, $\overline{KI2}$, $\overline{KI3}$, RXD0, CLK0		0.1	0.3	–	V
		$\overline{RESET}$		0.1	0.4	–	V
I_{IH}	Input “H” current		VI = 3 V, V_{CC} = 3 V	–	–	4.0	µA
I_{IL}	Input “L” current		VI = 0 V, V_{CC} = 3 V	–	–	–4.0	µA
R_{PULLUP}	Pull-up resistance		VI = 0 V, V_{CC} = 3 V	66	160	500	kΩ
V_{RAM}	RAM hold voltage		During stop mode	1.8	–	–	V

NOTE:
1. V_{CC} =2.7 to 3.3 V at T_{opr} = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.

Timing requirements
(Unless Otherwise Specified: V_{CC} = 3 V, V_{SS} = 0 V at T_{opr} = 25°C) [V_{CC} = 3 V]

Table 5.48 TRAIO Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRAIO)}$	TRAIO input cycle time	300	–	ns
$t_{WH(TRAIO)}$	TRAIO input “H” width	120	–	ns
$t_{WL(TRAIO)}$	TRAIO input “L” width	120	–	ns

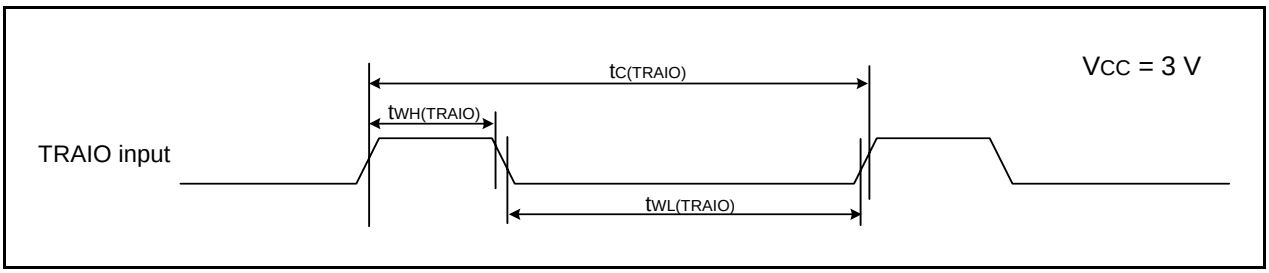


Figure 5.20 TRAIO Input Timing Diagram when V_{CC} = 3 V